

# **RP500x SERIES**

# 600mA\* Step-down DC/DC Converter with Synchronous Rectifier

NO.EA-155-111124

### OUTLINE

The RP500x Series are CMOS-based 600mA\* step-down DC/DC Converters with synchronous rectifier.

Each of these ICs consists of an oscillator, a switching control circuit, a reference voltage unit, an error amplifier, a soft-start circuit, protection circuits, UVLO circuit, switching transistors, and so on. A low ripple, high efficiency step-down DC/DC converter can be easily composed of this IC with only an inductor and capacitors.

In terms of the output voltage, since the feedback resistances are built-in, the voltage is fixed internally. 0.1V step output can be set by laser-trim and 1.5% or 24mV tolerance depending on the output voltage is guaranteed. Mode alternative circuit works automatically for improving the efficiency. Considering fixed noise frequency, PWM fixed control type is also available.

As protection circuits, the current limit circuit which limits peak current of Lx at each clock cycle, and the latch type protection circuit which works if the term of the over-current condition keeps on a certain time exist. The latch-type protection circuit works to latch an internal driver with keeping it disable. To release the condition of the protection, after disabling this IC with a chip enable circuit, enable it again, or restart this IC with power-on or make the supply voltage at UVLO detector threshold level or lower than UVLO.

Since packages are WLCSP-6-P2, DFN1616-6, DFN(PLP)1820-6, SOT-23-6W, high density mounting on boards is possible.

\*)This is an approximate value, because output current depends on conditions and external parts.

## **FEATURES**

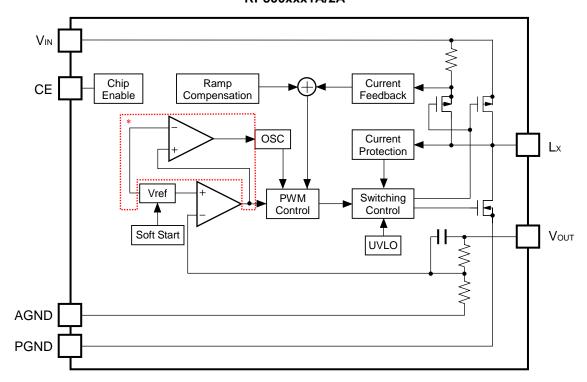
Supply Current	Typ. 400μA (at PWM mode)
	Typ. 100μA (at VFM mode)
Standby Current	Max. 5μA
Input Voltage Range	2.55V to 5.50V
Output Voltage Range	1.1V to 3.3V (0.1V steps)
	(For other voltages, please refer to MARK INFORMATIONS.)
Output Voltage Accuracy	±1.5% (Vουτ≥1.6V), ±24mV (Vουτ<1.6V)
Temperature-Drift Coefficient of Output Voltage.	Typ. ±100ppm/°C
Oscillator Frequency	Typ. 1.2MHz
Oscillator Maximum Duty Cycle	Min. 100%
Built-in Driver ON Resistance	Typ. Pch. 0.3Ω, Nch. 0.38Ω (V <sub>IN</sub> =3.6V)
UVLO Detector Threshold	Typ. 2.2V
Soft Start Time	Typ. 120μs
Lx Current Limit	Typ. 900mA
Latch type Protection Circuit	Typ. 1.5ms
Two choices of Switching Mode	Automatic PWM/VFM mode change / PWM fixed
Packages	WLCSP-6-P2, DFN1616-6, DFN(PLP)1820-6, SOT-23-6W

### **APPLICATIONS**

- Power source for battery-powered equipment.
- Power source for hand-held communication equipment, cameras, VCRs, camcorders.
- Power source for HDD, portable equipment.

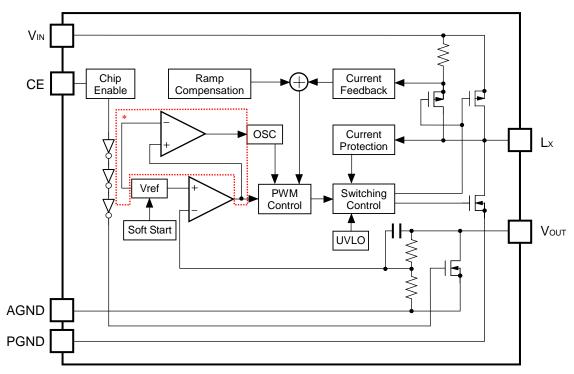
# **BLOCK DIAGRAMS**

#### RP500xxx1A/2A



\*) only RP500xxx1A for automatic PWM/VFM mode change

### RP500xxx3A/4A



\*) only RP500xxx3A for automatic PWM/VFM mode change

# **SELECTION GUIDE**

The output voltage, switching mode, and auto discharge function for the ICs can be selected at the user's request.

Product Name	Package	Quantity per Reel	Pb Free	Halogen Free
RP500Zxx*A-E2-F	WLCSP-6-P2	5,000 pcs	Yes	Yes
RP500Lxx*A-TR	DFN1616-6	5,000 pcs	Yes	Yes
RP500Kxx*A-TR	DFN(PLP)1820-6	5,000 pcs	Yes	Yes
RP500Nxx*A-TR-FE	SOT-23-6W	3,000 pcs	Yes	Yes

xx: The output voltage can be designated in the range from 1.1V(11) to 3.3V(33) in 0.1V steps\*1. (For other voltages, please refer to MARK INFORMATIONS.)

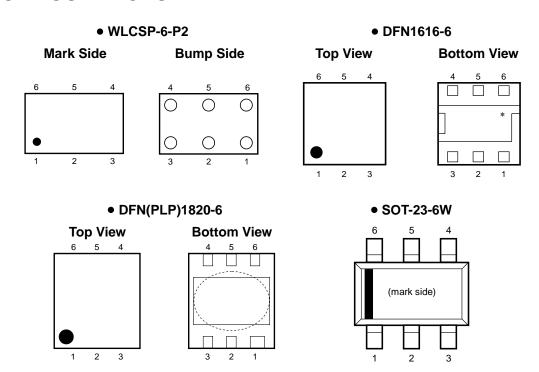
\* : The switching mode, and auto discharge function can be designated.

Code	Modulation method	Auto discharge function
1	PWM/VFM auto switching	No
2	PWM fixed	No
3	PWM/VFM auto switching	Yes
4	PWM fixed	Yes

(The RP500Kxx3A does not exist. Please use RP500Lxx3A.)

<sup>\*1) 0.05</sup>V step is also available as a custom code.

# PIN CONFIGURATIONS



# PIN DESCRIPTIONS

### • WLCSP-6-P2, SOT-23-6W

Pin No	Symbol	Pin Description		
1	Vоит	Output Pin		
2	PGND	Ground Pin		
3	Lx	Lx Switching Pin		
4	Vin	Input Pin		
5	AGND	Ground Pin		
6	CE	Chip Enable Pin ("H" Active)		

## DFN1616-6, DFN(PLP)1820-6

Pin No	Symbol	Pin Description	
1	CE	Chip Enable Pin ("H" Active)	
2	AGND	Ground Pin	
3	Vin	Input Pin	
4	Lx	Lx Switching Pin	
5	PGND	Ground Pin	
6	Vouт	Output Pin	

<sup>\*)</sup> Tab is GND level. (They are connected to the reverse side of this IC.)

The tab is better to be connected to the GND, but leaving it open is also acceptable.

# **ABSOLUTE MAXIMUM RATINGS**

AGND=PGND=0V

Symbol	Item	Rating	Unit	
Vin	Input Voltage	-0.3 to 6.5	V	
$V_{Lx}$	Lx pin Voltage	-0.3 to V <sub>IN</sub> +0.3	V	
Vce	CE Pin Input Voltage	-0.3 to 6.5	V	
Vouт	Output Voltage	-0.3 to 6.5	V	
ILx	Lx Pin Output Current	800	mA	
	Power Dissipation (WLCSP-6-P2) *	650		
PD	Power Dissipation (DFN1616-6) *	640	mW	
FD	Power Dissipation (DFN(PLP)1820-6) *	880	IIIVV	
	Power Dissipation (SOT-23-6W) *	430		
Topt	Operating Temperature Range	-40 to 85	°C	
Tstg	Storage Temperature Range	-55 to 125	°C	

<sup>\*)</sup> For Power Dissipation, please refer to PACKAGE INFORMATION.

#### **ABSOLUTE MAXIMUM RATINGS**

Electronic and mechanical stress momentarily exceeded absolute maximum ratings may cause the permanent damages and may degrade the life time and safety for both device and system using the device in the field. The functional operation at or over these absolute maximum ratings is not assured.

# **ELECTRICAL CHARACTERISTICS**

• **RP500x** Topt=25°C

Symbol	Item	Conditions		Min.	Тур.	Max.	Unit
Vin	Operating Input Voltage			2.55		5.5	V
Vouт	Output Voltage	V <sub>IN</sub> =V <sub>CE</sub> =3.6V V <sub>OUT</sub> ≥ 1.6	V <sub>OUT</sub> ≥ 1.6V	×0.985		×1.015	V
<b>V</b> 001	Output Voltage	or Set Vouт+1V	Vout < 1.6V	-24		24	mV
$\Delta$ Vουτ/ $\Delta$ Topt	Output Voltage Temperature Coefficient	-40°C≤Topt≤85	5°C		±100		ppm /°C
fosc	Oscillator Frequency	VIN=VCE=3.6V	or Set Vo∪⊤+1V	0.96	1.2	1.44	MHz
I <sub>DD1</sub>	Supply Current 1	VIN=VCE=5.5V,	Vоит=0V		400	500	μΑ
I <sub>DD2</sub>	Supply Current 2	VIN=VCE=VOUT	PWM/VFM		100	160	μА
IDD2	Supply Suitent 2	=5.5V	PWM fixed		400	500	μΛ
İstandby	Standby Current	VIN=5.5V, VCE=	0V		0	5	μΑ
RONP	ON Resistance of Pch Tr.	VIN=3.6V, ILX=-	100mA		0.3		Ω
Ronn	ON Resistance of Nch Tr.	V <sub>IN</sub> =3.6V, I <sub>LX</sub> =-100mA			0.38		Ω
ILXleakH	Lx Leakage Current "H"	VIN=VLX=5.5V, VCE=0V		-1	0	5	μΑ
LXleakL	Lx Leakage Current "L"	VIN=5.5V, VCE=VLX=0V		-5	0	1	μΑ
Іνоитн	Vouт "H" Input Current *1	VIN=VOUT=5.5V, VCE=0V		-1	0	1	μΑ
IVOUTL	Vouт "L" Input Current	VIN=5.5V, VCE=VOUT=0V		-1	0	1	μΑ
Ісен	CE "H" Input Current	VIN=VCE=5.5V		-1	0	1	μΑ
ICEL	CE "L" Input Current	VIN=5.5V, VCE=	0V	-1	0	1	μΑ
Vсен	CE Input Voltage "H"	VIN=5.5V		1.0			V
Vcel	CE Input Voltage "L"	VIN=5.5V				0.4	V
Maxduty	Oscillator Maximum Duty Cycle			100			%
tstart	Soft-start Time	VIN=VCE=3.6V	VIN=VCE=3.6V or Set VOUT+1V		120	150	μS
LXlim	Lx Current Limit	VIN=VCE=3.6V or Set VOUT+1V		600	900		mA
tprot	Protection Delay Time	VIN=VCE=3.6V or Set VOUT+1V		0.5	1.5	5.0	ms
Vuvlo1	UVLO Detector Threshold	V <sub>IN</sub> =V <sub>CE</sub>		2.1	2.2	2.3	V
V <sub>UVLO2</sub>	UVLO Released Voltage	V <sub>IN</sub> =V <sub>CE</sub>		2.2	2.3	2.4	V
RLOW	Low Output Nch Tr. ON Resistance *2	VIN=3.6V, VCE=	0V		80		Ω

Test circuit is "OPEN LOOP" and AGND=PGND=0V unless otherwise noted.

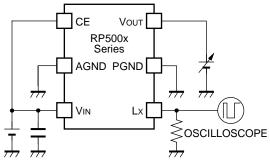
## RECOMMENDED OPERATING CONDITIONS (ELECTRICAL CHARACTERISTICS)

All of electronic equipment should be designed that the mounted semiconductor devices operate within the recommended operating conditions. The semiconductor devices cannot operate normally over the recommended operating conditions, even if when they are used over such conditions by momentary electronic noise or surge. And the semiconductor devices may receive serious damage when they continue to operate over the recommended operating conditions.

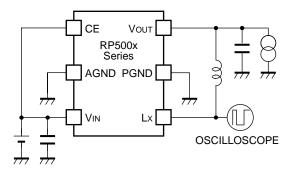
<sup>\*1)</sup> without auto discharge version only

<sup>\*2)</sup> with auto discharge version only

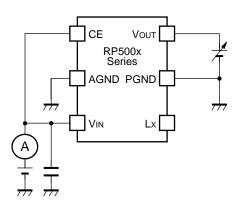
# **TEST CIRCUITS**



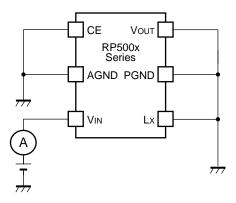
**Output Voltage** 



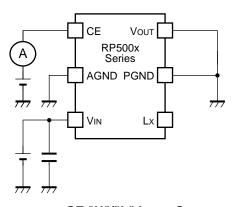
**Oscillator Frequency** 



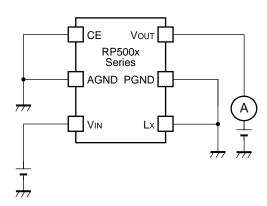
**Supply Current 1,2** 



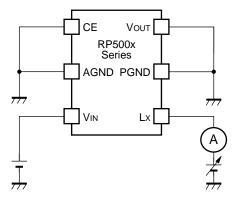
**Standby Current** 



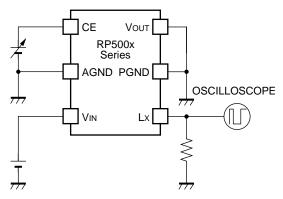
**CE "H"/"L" Input Current** 



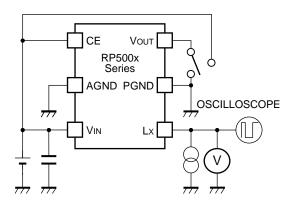
VOUT "H"/"L" Current



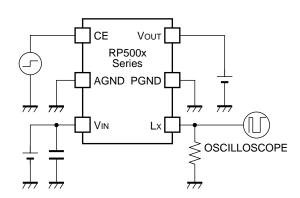
Lx Leakage Current



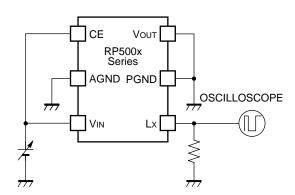
**CE Input Voltage** 



Pch • Nch transistor ON resistance /
Output Delay for Protection / Lx Current limit

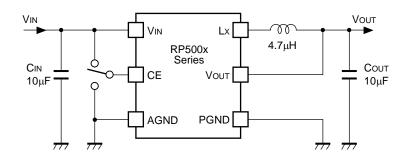


**Soft-start Time** 



**UVLO Detector Threshold • Released Voltage** 

## TYPICAL APPLICATION



Symbol	Parts Recommendation			
Cin	10μF	Ceramic	C2012JB0J106K (TDK)	
Соит	10μF	Ceramic	C2012JB0J106K (TDK)	
L	4.7μΗ	VLF3010A	T-4R7MR30	

## **TECHNICAL NOTES**

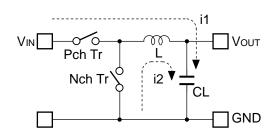
When using these ICs, consider the following points:

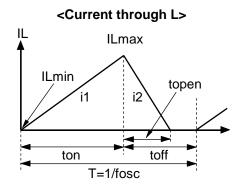
- Set the same level as AGND and PGND.
- Set external components such as an inductor, CIN, COUT as close as possible to the IC, in particular, minimize the wiring to VIN pin and PGND pin. Reinforce the VIN, PGND, and VOUT lines sufficiently. Large switching current may flow in these lines. If the impedance of VIN and PGND lines is too large, the internal voltage level in this IC may shift caused by the switching current, and the operation might be unstable. The wiring between VOUT and load and between L and VOUT should be separated.
- · Use an external capacitor C<sub>IN</sub> between V<sub>IN</sub> and GND, and C<sub>OUT</sub> with a capacity of 10µF or more ceramic type.
- · Choose an inductor with inductance range from  $4.7\mu H$  to  $10\mu H$ . The phase compensation has been made by these values with output capacitors. The recommendation characteristics of the inductor are low DC resistance, large enough permissible current, and strong against the magnetic saturation. Inductance value may shift depending on an inductor. If the inductance value at an actual load current is low, Lx peak current may increase and may overlap the Lx current limit. As a result, over current protection may work.
- · Over current protection circuit may be affected by self-heating and heat radiation environment.
- \*The performance of power source circuits using these ICs extremely depends upon the peripheral circuits. Pay attention in the selection of the peripheral circuits. In particular, design the peripheral circuits in a way that the values such as voltage, current, and power of each component, PCB patterns and the IC do not exceed their respected rated values. (such as the voltage, current, and power)

# Operation of step-down DC/DC converter and Output Current

The DC/DC converter charges energy in the inductor when Lx transistor is ON, and discharges the energy from the inductor when Lx transistor is OFF and controls with less energy loss, so that a lower output voltage than the input voltage is obtained. The operation will be explained with reference to the following diagrams:

#### <Basic Circuit>





- Step 1: Pch Tr. turns on and current IL (=i1) flows, and energy is charged into CL. At this moment, IL increases from ILmin (=0) to reach ILmax in proportion to the on-time period (ton) of Pch Tr.
- Step 2: When Pch Tr. turns off, Synchronous rectifier Nch Tr. turns on in order that L maintains IL at ILmax, and current IL (=i2) flows.
- Step 3: IL (=i2) decreases gradually and reaches IL=ILmin=0 after a time period of topen, and Nch Tr. turns off. Provided that in the continuous mode, next cycle starts before IL becomes to 0 because toff time is not enough. In this case, IL value increases from this ILmin (>0).

In the case of PWM control system, the output voltage is maintained by controlling the on-time period (ton), with the oscillator frequency (fosc) being maintained constant.

The maximum value (ILmax) and the minimum value (ILmin) of the current flowing through the inductor are the same as those when Pch Tr. turns on and off.

The difference between ILmax and ILmin, which is represented by  $\Delta I$ :

$$\Delta I = ILmax - ILmin = Vout \times topen / L = (V_{IN} - Vout) \times ton / L$$
 Equation 1

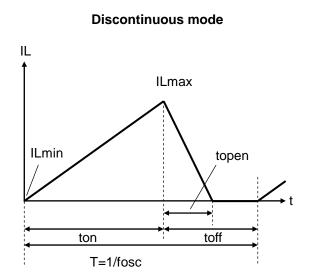
wherein,

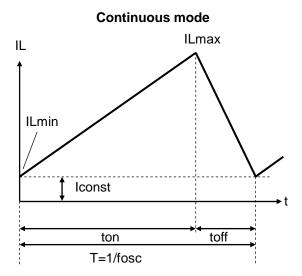
$$T = 1 \text{ / fosc} = ton + toff$$
 
$$duty \text{ (\%)} = ton \text{ / } T \times 100 = ton \times fosc \times 100$$
 
$$topen \leq toff$$

In Equation 1,  $V_{OUT} \times t_{OPEN} / L$  and  $(V_{IN} - V_{OUT}) \times t_{ON} / L$  respectively show the change of the current at "OFF".

### Discontinuous mode and Continuous mode

When the output current (IouT) is relatively small, topen < toff as illustrated in the following diagram. In this case, the energy is charged in the inductor during the time period of ton and is discharged in its entirely during the time period of toff, therefore ILmin becomes to zero (ILmin=0). When IouT is gradually increased, eventually, topen becomes to toff (topen=toff), and when IouT is further increased, ILmin becomes larger than zero (ILmin>0). The former mode is referred to as the discontinuous mode and the latter mode is referred to as continuous mode.





In the continuous mode, when Equation 1 is solved for ton and assumed that the solution is tone,

$$tonc = T \times V_{OUT} / V_{IN}$$
 Equation 2

When ton<tonc, the mode is the discontinuous mode, and when ton=tonc, the mode is the continuous mode.

# **Output Current and selection of External components**

The relation between the output current and external components is as follows:

When Pch Tr. of Lx is ON:

(Wherein, Ripple Current p-p value is described as  $I_{RP}$ , ON resistance of Pch Tr. and Nch Tr. of Lx are respectively described as  $R_{ONP}$  and  $R_{ONN}$ , and the DC resistor of the inductor is described as  $R_{L}$ .)

$$V_{IN} = V_{OUT} + (R_{ONP} + R_L) \times I_{OUT} + L \times I_{RP} / t_{ON}$$
 Equation 3

When Pch Tr. of Lx is "OFF" (Nch Tr. is "ON"):

$$L \times IRP \ / \ to \textit{ff} = Ronn \times Iout + Vout + R_L \times Iout \ ...$$
 Equation 4

Put Equation 4 to Equation 3 and solve for ON duty of Pch transistor,  $D_{ON} = ton / (toff + ton)$ ,

$$Don = (Vout + Ronn \times Iout + RL \times Iout) / (Vin + Ronn \times Iout - Ronp \times Iout) \dots Equation 5$$

Ripple Current is as follows:

$$I_{RP} = (V_{IN} - V_{OUT} - R_{ONP} \times I_{OUT} - R_{L} \times I_{OUT}) \times D_{ON} / fosc / L.$$
Equation 6

wherein, peak current that flows through L, and Lx Tr. is as follows:

$$ILxmax = Iout + Irp/2$$
 Equation 7

Consider ILxmax, condition of input and output and select external components.

<sup>\*</sup>The above explanation is directed to the calculation in an ideal case in continuous mode.

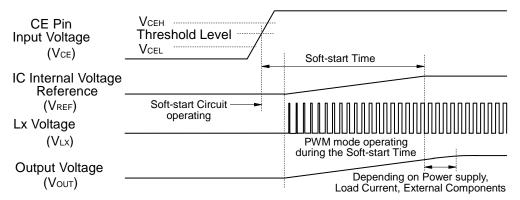
### TIMING CHART

#### (1) Soft Start Time

#### In the case of starting this IC with CE

In the case of starting this IC with CE, the operation can be as in the timing chart below.

When the voltage of CE pin ( $V_{CE}$ ) is beyond the threshold level, the operation of the IC starts. The threshold voltage of CE pin is in between CE "H" input voltage ( $V_{CEH}$ ) and CE "L" input voltage ( $V_{CEL}$ ) described in the electrical characteristics table. Soft-start circuit operates, and after the certain time, the reference voltage inside the IC ( $V_{REF}$ ) is rising gradually up to the constant value.



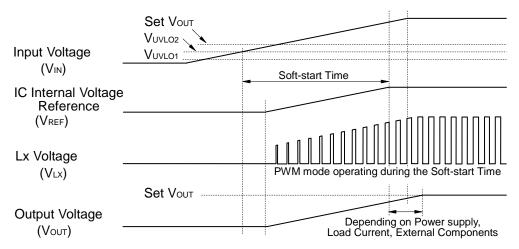
Soft-start time is the time interval from soft start circuit starting point to the reference voltage level reaching point up to this constant level.

\*Soft start time is not always equal to the turn-on speed of DC/DC converter.

The power supply capacity for this IC, load current, inductance and capacitance values affect the turn-on speed.

#### In the case of starting with power supply

In the case of starting with power supply, when the input voltage  $(V_{IN})$  is larger than UVLO released voltage  $(V_{UVLO2})$ , soft start circuit operates, and after that, the same explanation above is applied to the operation. Soft-start time is the time interval from soft start circuit starting point to the reference voltage level reaching point up to this constant level.

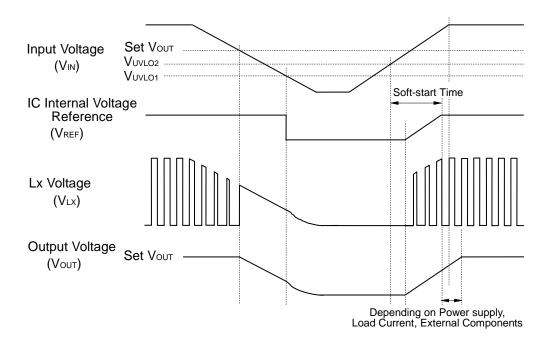


- \*Turn-on speed is affected by next conditions;
- (a) Input Voltage (V<sub>IN</sub>) rising speed depending on the power supplier to the IC and input capacitor C<sub>IN</sub>.
- (b) Output Capacitor Cout value and load current value.

## (2) Under Voltage Lockout (UVLO) Circuit

The step-down DC/DC converter stops and ON duty becomes 100%, if input voltage  $(V_{IN})$  becomes less than the set output voltage (Set  $V_{OUT}$ ), the output voltage  $(V_{OUT})$  gradually drops according to the input voltage  $(V_{IN})$ . If the input voltage drops more and becomes less than UVLO detector threshold  $(V_{UVLO1})$ , the under voltage lockout circuit (UVLO) operates, the IC internal reference voltage  $(V_{REF})$  stops, switching transistors turn off and the output voltage drops according to the load and output capacitor  $C_{OUT}$  value. To restart the normal operation, the input voltage  $(V_{IN})$  must be more than the UVLO released voltage  $(V_{UVLO2})$ .

The timing chart below describes the operation with varying the input voltage (V<sub>IN</sub>).



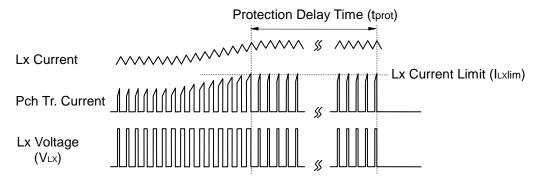
<sup>\*</sup>Actually, the waveform of Vout at UVLO working and releasing varies depending on the initial voltage of Cout and load current situation.

#### (3) Over Current Protection Circuit, Latch Type Protection Circuit

Over current protection circuit supervises the coil peak current (the current flowing Pch transistor) at each switching cycle, and if the current beyond the Lx current limit (I<sub>LXIim</sub>), Pch transistor is turned off. the Lx current limit of RP500x is Typ.900mA.

Further, if the over current status continues equal or longer than protection delay time, or, when the Lx limit current is exceeded even once when the driver operates by duty 100%, a built-in driver is latched in the OFF state and the operation of DC/DC converter stops.

\*Lx current limit and protection delay time is affected by self-heating and ambient environment. If the output is short and the input voltage (V<sub>IN</sub>) is drastically dropped or becomes unstable, the protection operation and delay time may vary.

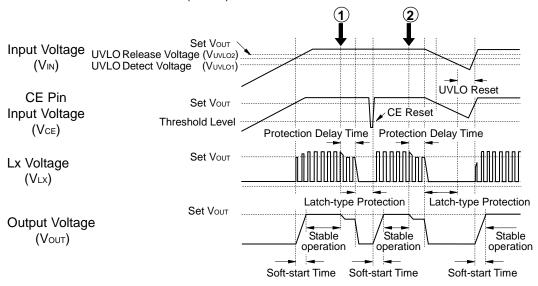


To release the condition of latch type protection, restart this IC by inputting "L" signal to CE pin, or restart this IC with power-on or make the supply voltage lower than UVLO detector threshold (V<sub>UVLO1</sub>) level.

The timing chart shown below describes the changing process of input voltage rising, stable operating, operating with large current, reset with CE pin, stable operating, input voltage falling, input voltage recovering, and stable operating.

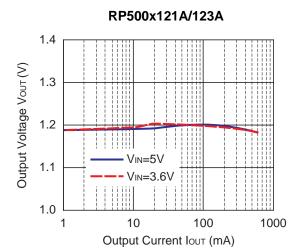
If too large current flows through the circuit because of short or other reasons, after the delay time of latch type protection a built-in driver is latched in the OFF state and  $V_{LX}$  signal will be "L", then output will turn off. At the point (1), release the latch type protection is realized with CE reset as changed CE signal from "L" to "H".

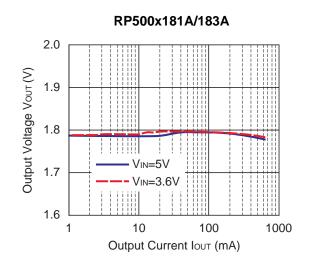
At the point (2), release the latch type protection is realized with UVLO reset as make the supply voltage lower than UVLO detector threshold ( $V_{UVLO1}$ ) level.

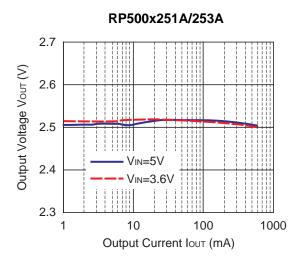


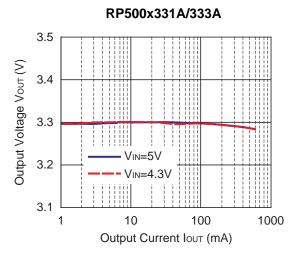
# **TYPICAL CHARACTERISTICS**

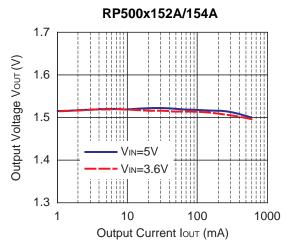
# 1) Output Voltage vs. Output Current



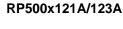


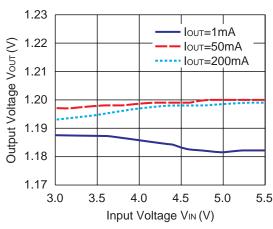


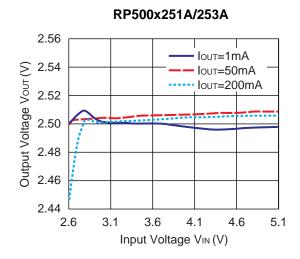




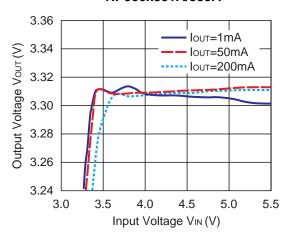
## 2) Output Voltage vs. Input Voltage



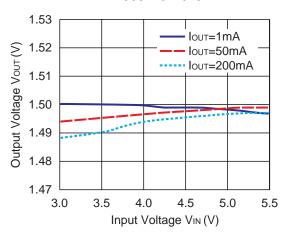




#### RP500x331A/333A

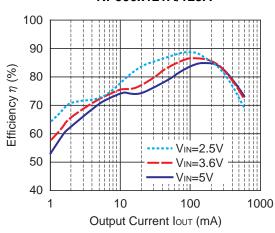


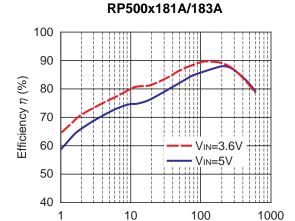
#### RP500x152A/154A



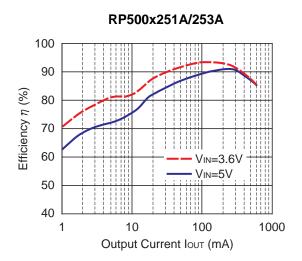
# 3) Efficiency vs. Output Current

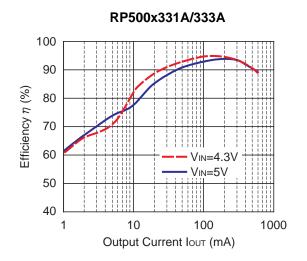
#### RP500x121A/123A

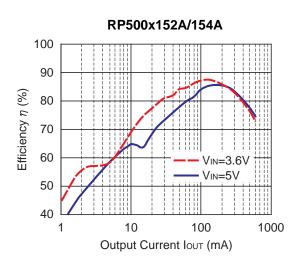




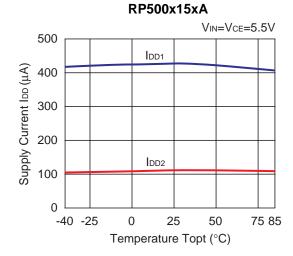
Output Current Iout (mA)



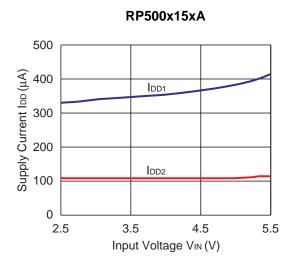




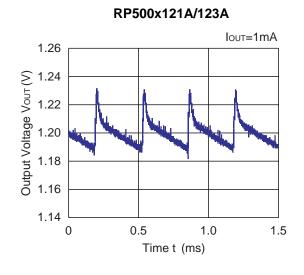
# 4) Supply Current 1, 2 vs. Temperature

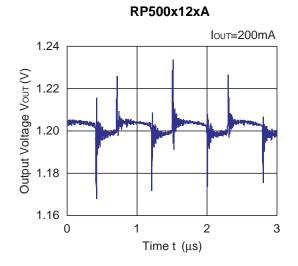


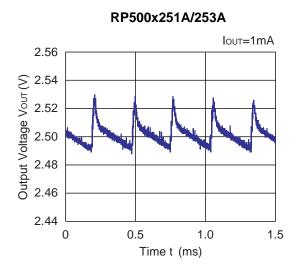
# 5) Supply Current 1, 2 vs. Input Voltage

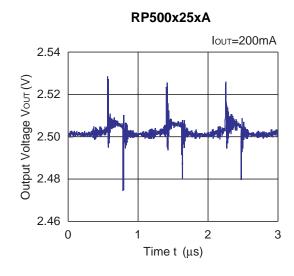


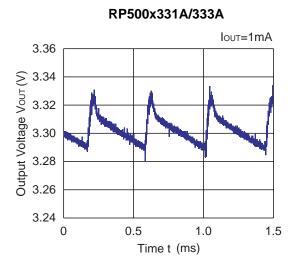
# 6) DC/DC Output Waveform (CiN=Cout=10μF, L=4.7μH)

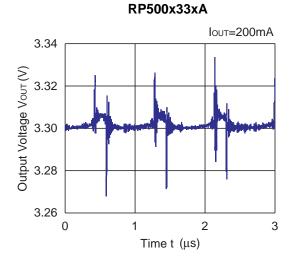




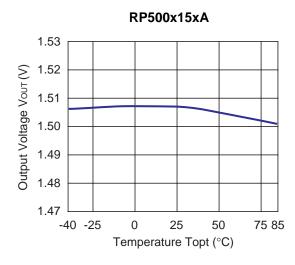


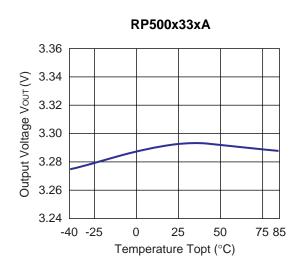




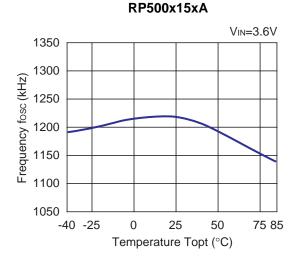


### 7) Output Voltage vs. Temperature



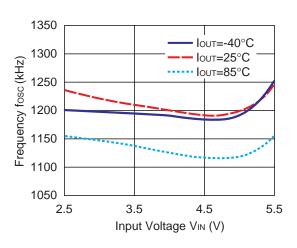


# 8) Oscillator Frequency vs. Temperature

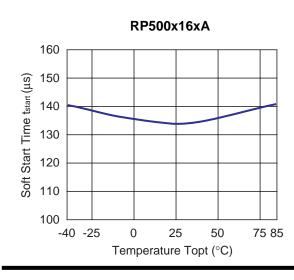


9) Oscillator Frequency vs. Input Voltage

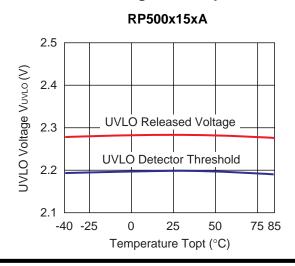
RP500x15xA



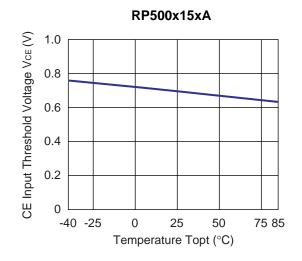
# 10) Soft-start Time vs. Temperature



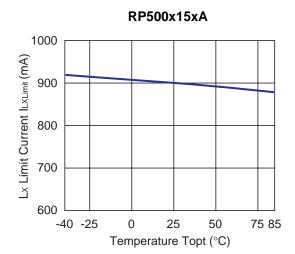
11) UVLO Detector Threshold/ Released Voltage vs. Temperature



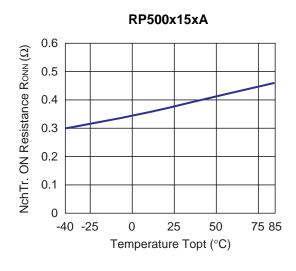
## 12) CE Input vs. Temperature



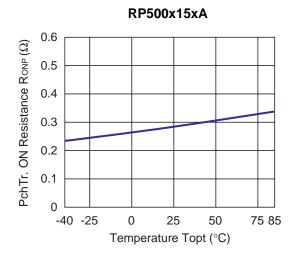
#### 13) Lx Current Limit vs. Temperature



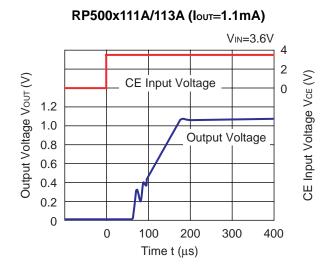
14) Nch Tr. ON Resistance vs. Temperature



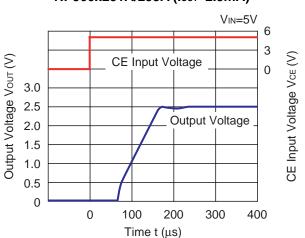
15) Pch Tr. ON Resistance vs. Temperature

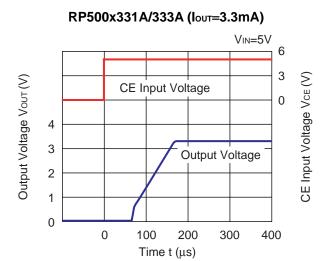


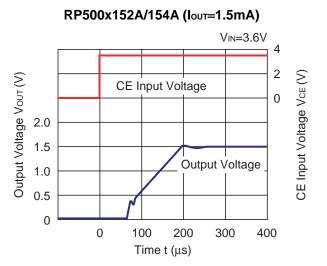
16) Turn on speed with CE pin (CiN=Cout=Ceramic 10μF, L=4.7μH)



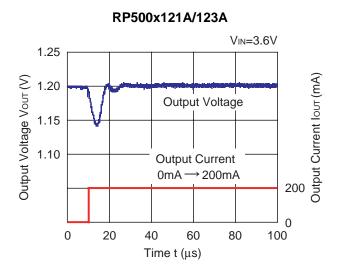
# RP500x251A/253A (Iout=2.5mA)

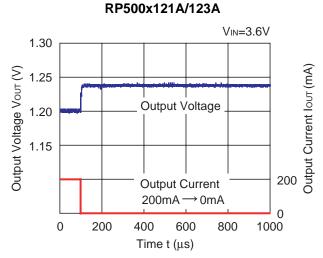


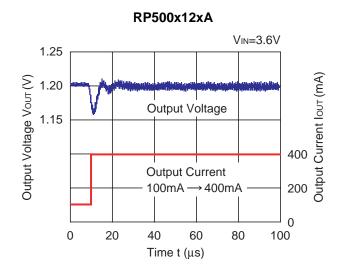


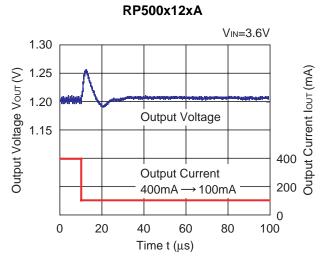


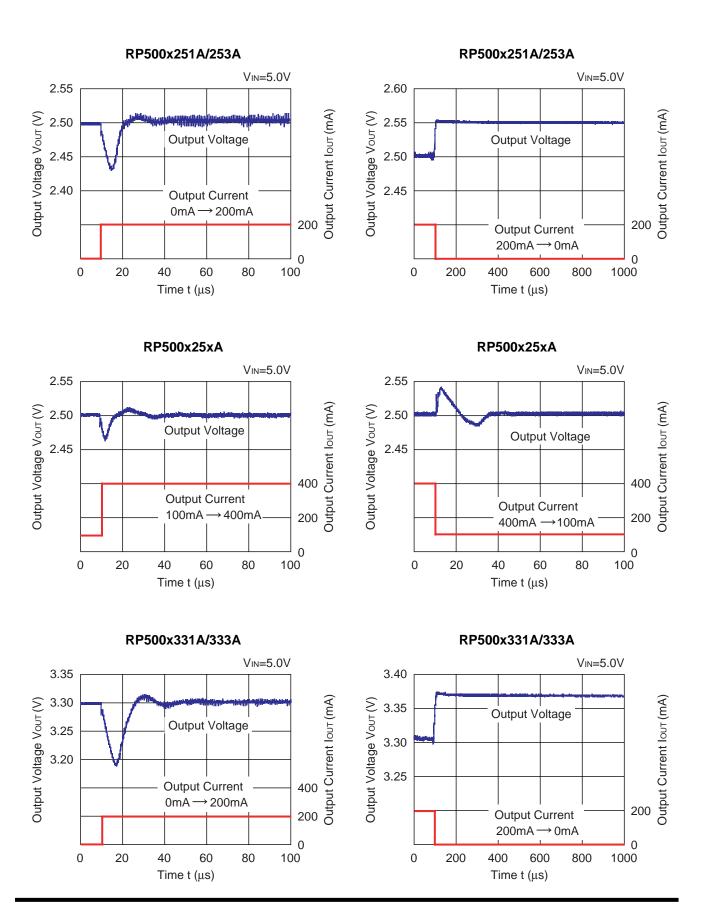
## 17) Load Transient Response (CIN=COUT=Ceramic 10μF, L=4.7μH)

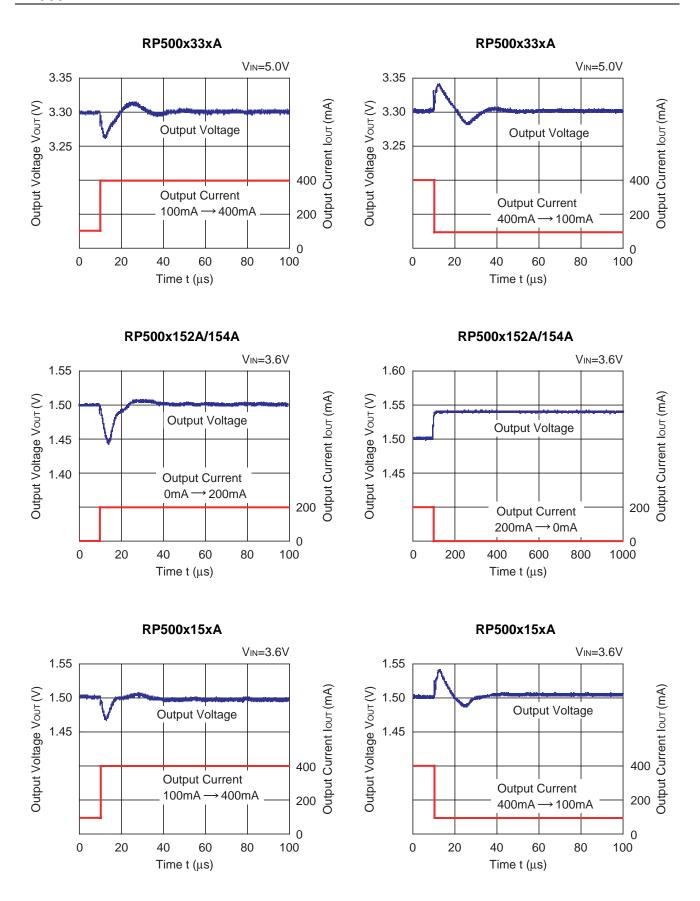














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